CMT802XNXL High-Speed, Dual-Channel Digital Isolator

1 Features

- Safety-related certifications
  - DIN VDE V 0884-11: 2017-01
  - UL 1577 component recognition program
  - CSA certification according to IEC 60950-1, IEC 62368-1, IEC 61010-1 and IEC 60601-1 end equipment standards
  - CQC approval per GB4943.1-2022
  - TUV certification according to EN 60950-1, EN 62368-1 and EN 61010-1
- Robust electromagnetic compatibility
  - System-level ESD, EFT, and surge immunity
  - ±8 kV IEC 61000-4-2 contact discharge protection across isolation barrier
  - Low emissions
- Data rate: up to 10 Mbps
- Wide supply range: 2.5 to 5.5 V
- Operation temperature: -40°C to 125°C
- Robust isolation barrier
  - More than 40-year projected lifetime
  - Up to 3.75 kV_{RMS} isolation rating
  - Up to 5.3 kV surge capability
  - ±200 kV/μs typical CMTI
- Default output high or low options
- Low power consumption, typical 1.5 mA per channel at 1 Mbps
- Low propagation delay: 9 ns typical (5V supplies)
- SOIC 8 package (narrow body)

2 Applications

- Industrial automatic control
- New energy vehicles
- Solar inverters
- Motor control
- Isolated SPI
- General purpose multichannel isolation

3 Description

The CMT802XNXL series devices are high-performance, dual channel digital isolators with as high as 3.75 kV_{rms} isolation voltage by means of silicon-dioxide (SiO2) insulation barrier.

The digital isolator is used to communicate between two different power supply domains while prevents noise currents on a data bus or other circuits from entering the local ground and interfering with or damaging sensitive circuitry.

This device comes with enable pins that can be used to put the respective outputs in high impedance for multi-master driving applications and to reduce power consumption. The CMT802XNXL device has four forward and up to two reverse-direction channels. If the input power or signal is lost, the default output is high for the CMT802XN1L device and low for the CMT802XN0L device. See the Device Functional Modes section for further details.

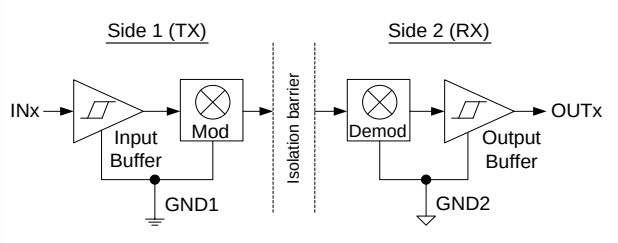
The isolator provides high electromagnetic immunity and low emissions at low-power consumption. Through innovative chip design and layout techniques, electromagnetic compatibility of the CMT802XNXL device has been significantly enhanced to ease system-level ESD, EFT, surge, and emissions compliance.

The CMT802XNXL series device is available in narrow-body (NB) 8-pin SOIC package.

Device Information

Part No.	Package	Body Size (mm x mm)
CMT802XNXL	NB(N) SOIC-8	5.0 x 3.9
Refer to section 14 for ordering information.		

Simplified Schematic



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4 Absolute Maximum Ratings

Table 1. Absolute Maximum Ratings[1]

Parameters	Symbol	Condition	Min.	Max.	Unit
Power supply voltage[2]	VDD1, VDD2		-0.5	6.5	V
Maximum input voltage	INx	x = A, B	-0.4	VDD+0.4	V
Maximum output voltage	OUTx	x = A, B	-0.4	VDD+0.4	V
Maximum Input / output pulse voltage	-	Pulse width should be less than 100 ns, and the duty cycle should be less than 10%	-0.8	VDD+0.8	V
Common-mode transient immunity	CMTI			±200	kV/us
Output current	I_O		-15	15	mA
Maximum surge immunity	-			5.3	kV
Operating temperature	T_A		-40	125	℃
Storage temperature	T_{STG}		-40	150	℃

Notes:

[1]. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

[2]. All voltage values except differential I/O bus voltages are with respect to the local ground terminal (GND1 or GND2) and are peak voltage values.

5 Recommended Operating Conditions

Table 2. Recommended Operating Conditions

Parameters	Symbol	Condition	Min.	Typ.	Max.	Unit
Power supply voltage	VDD1, VDD2		2.5	5	5.5	V
High level input voltage	V_{IH}	VDDI: input side VDD	0.7*VDD		VDDI	V
Low level input voltage	V_{IL}	VDDI: input side VDD	0		0.3VDD	V
Data rate	DR		0		10	Mbps
Operating temperature	T_A		-40	25	125	℃
Junction temperature	T_J		-40		150	℃

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6 ESD Ratings

Table 3. ESD Ratings

Parameter	Symbol	Condition	Max.	Unit
Electrostatic discharge	V_{ESD}	Human-body model (HBM)	±8000	V
		Charged-device model (CDM)	± 2000	

Notes:

1. IEC ESD strike is applied across the barrier with all pins on each side tied together creating a two-terminal device.
2. Testing is carried out in air or oil to determine the intrinsic contact discharge capability of the device.



Caution! ESD sensitive device. Precaution should be used when handling the device in order to prevent performance degradation or loss of functionality.

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7 Pin Description

The series part number CMT8020NXL, CMT8021NXL and CMT8022NXL are available for narrow-body (N) 8-pin SOIC package. The pin lists are shown as below.

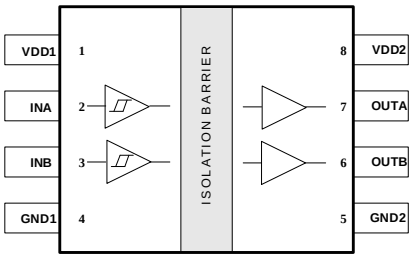


Figure 1. CMT8020NXL Pin List

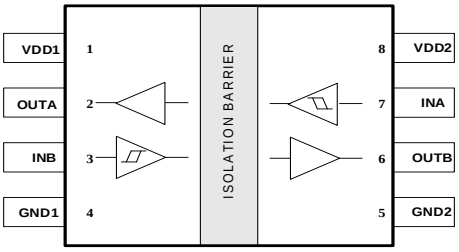


Figure 2. CMT8021NXL Pin List

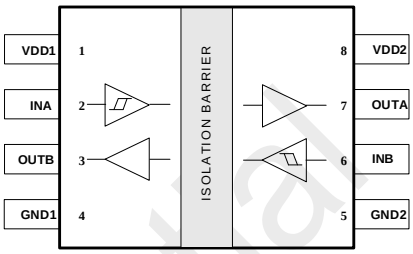


Figure 3. CMT8022NXL Pin List

Table 4. CMT8020 / 21 / 22NXL Pin Description

Pin Name	Pin Nmuber			I/O	Description
	NB SOIC-8				
	CMT8020N	CMT8021N	CMT8022N		
GND1	4	4	4	-	Left ground
GND2	5	5	5	-	Right ground
INA	2	7	2	I	Input, channel A
INB	3	3	6	I	Input, channel B
OUTA	7	2	7	O	Output, channel A
OUTB	6	6	3	O	Output, channel B
V_{DD1}	1	1	1	-	Power supply for left side
V_{DD2}	8	8	8	-	Power supply for right side

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8 Typical Application

8.1 Typical Application Schematic

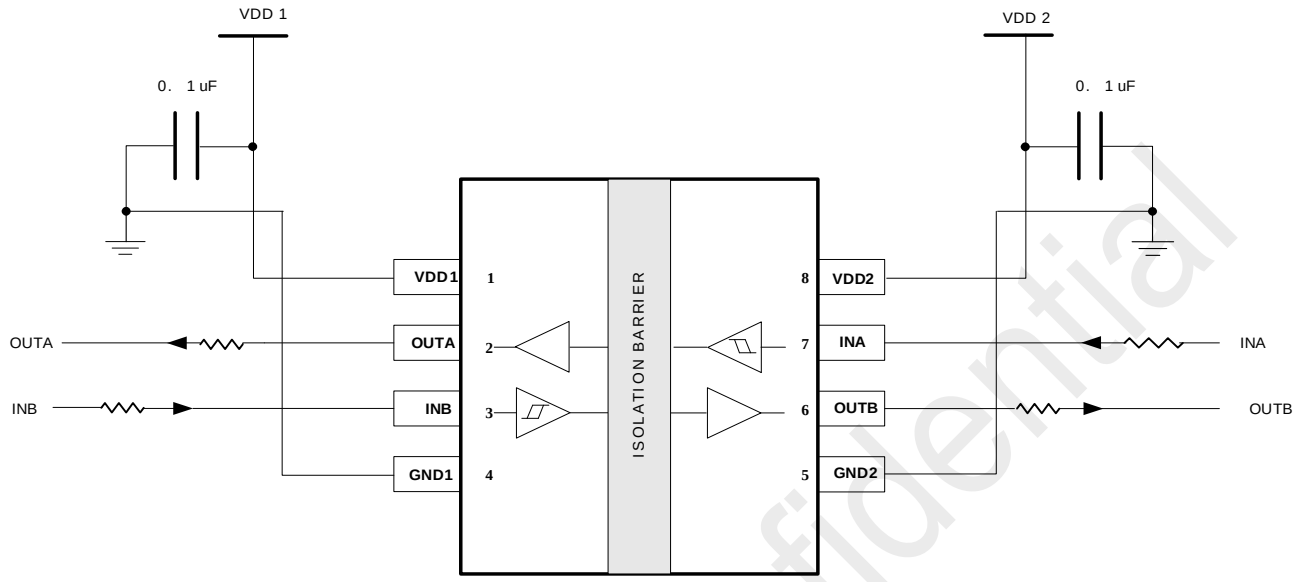


Figure 7. Typical Application Schematic (Take the CMT8021NXL as an example)

Note: *users should be careful not to connect ground and VDD reversely*

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8.2 PCB Layout Guidelines

The CMT802XNXL requires a 0.1 µF bypass capacitor in both input side and output side. The capacitor should be placed as close as possible to the package pin of VDD1 and VDD2 respectively. The figures below show the recommended PCB layout. Please make sure the space under the chip keeps free from planes, traces, pads and via. To enhance the robustness of design, users may also include resistors (50 ~ 300 Ω) in series with the inputs and outputs if the system is excessively noisy. The series resistors also improve the system reliability such as latch-up immunity.

The typical output impedance of an isolator driver channel is approximately 50 Ω ± 40%. When driving loads where transmission line effects will be a factor, output pins should be appropriately terminated with controlled impedance PCB traces.

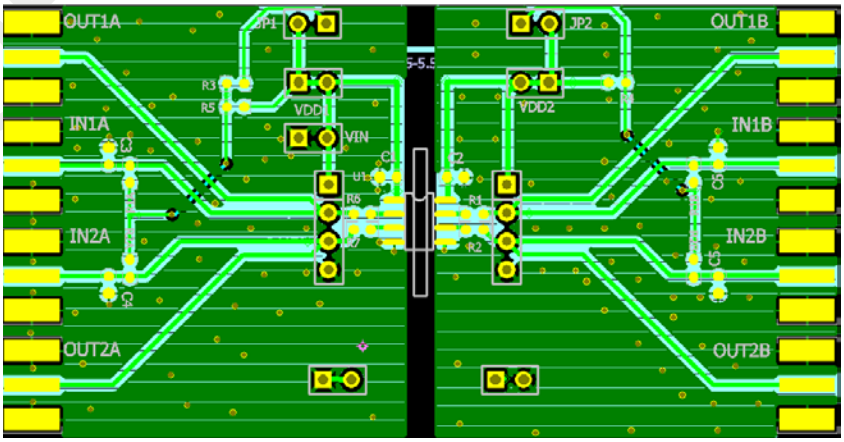


Figure 8. Recommended PCB Layout

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9 Parameter Measurement Circuit Setup

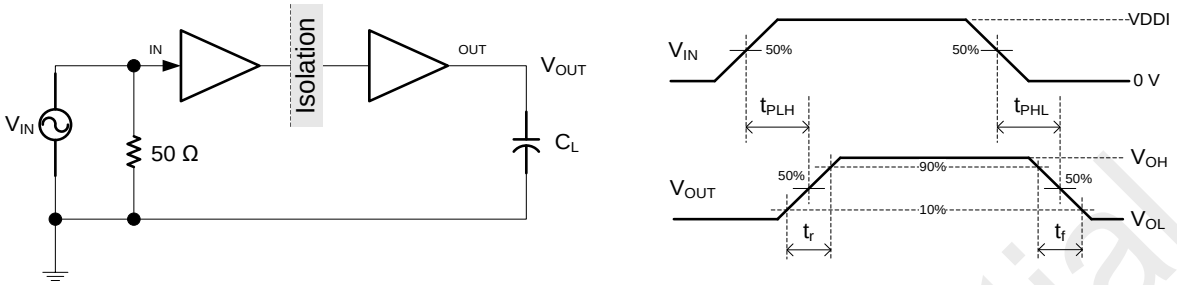


Figure 9. Switching Characteristics Test Circuit and Voltage Waveforms

Notes:

1. The input pulse is supplied by a generator V_{IN} having the following characteristics: f_{PULSE} ≤ 100 kHz, 50% duty cycle, t_r ≤ 3 ns, t_f ≤ 3 ns, Z_O = 50 Ω. At the input, 50 Ω resistor is required to terminate input generator signal. It is not needed in actual application.
2. Load capacitance influences the measurement results quite a lot, including instrumentation and fixture capacitance, totally no more than 15 pF loading is preferred.

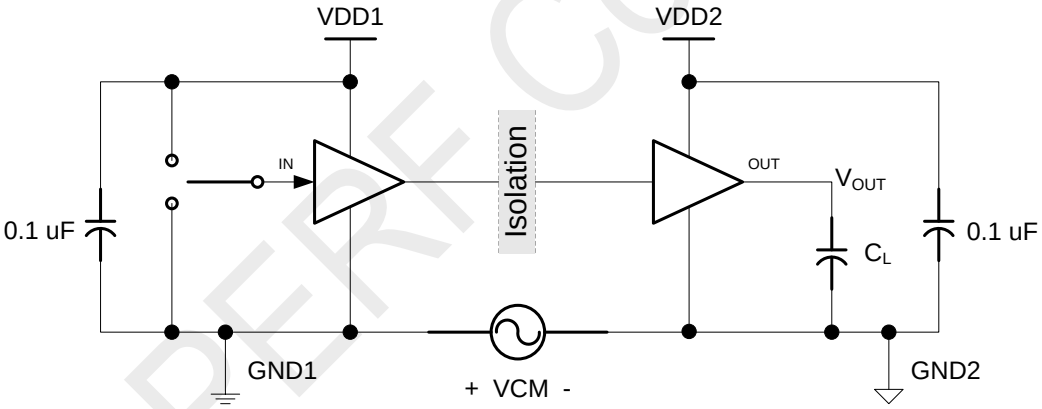


Figure 10. Common-Mode Transient Immunity Test Circuit

Notes:

1. CL = 15 pF, the total instrumentation and connection is within ±20%.

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10 Electrical Specifications

10.1 Electrical Characteristics

VDD1 =2.5V~5.5V, VDD2= 3.0V~5.5V, TA= -40 to 125 ℃. Unless otherwise noted, typical values are at VDD1=5V, VDD2=5V, TA=25 ℃.

Table 5. Electrical Characteristics

Parameters	Symbol	Condition	Min.	Typ.	Max.	Unit
Poweron reset	V_{POR}	POR threshold as during power- up		2.3		V
	V_{HYS}	POR threshold hysteresis		0.1		V
Input threshold	V_{IT}	Input threshold at rising edge			0.7*VDD1	V
	V_{IT-}	Input threshold at falling edge	0.3*VDD1			V
	V_{ITHYS}	Input threshold hysteresis		0.2*VDD1		V
High level output voltage	V_{OH}	I_{OH} = -4mA	VDD- 0.3			V
Low level output voltage	V_{OL}	I_{OL} = 4mA			0.3	V
Output impedance	R_O			50		Ω
Input pull high or low current	Ipull			10	15	uA
Start-up time after POR	trbs			10		us
Common mode transient	CMTI			200		kV/us

10.2 Supply Current Characteristics with 5 V Supply

VDD1 = VDD2 = 5V, T_A= -40 to 125 ℃.

Table 6. Supply Current Characteristics with 5 V Supply

Parameter	Symbol	Typ.	Max.	Unit
CMT8020NXL				
Supply current EN = VDDI,V_{IN} =0 V	I_{DD1}	0.67		mA
	I_{DD2}	1.14		mA
Supply current: device is disabled. EN = VDDI,V_{IN} =VDDI,	I_{DD1}	2.96		mA
	I_{DD2}	1.19		mA
Supply current: 1 Mbps square wave clock input AC signal. All channels switching with 1 Mbps square wave input, C_L = 15 pF	I_{DD1}	1.82		mA
	I_{DD2}	1.34		mA
Supply current: 10 Mbps square wave clock input AC signal. All channels switching with 10 Mbps square wave input, C_L = 15 pF	I_{DD1}	1.85		mA
	I_{DD2}	2.84		mA
CMT8021NXL				
Supply current EN = VDDI, V_{IN} =0 V	I_{DD1}	1.12		mA
	I_{DD2}	1.14		mA
Supply current: device is disabled. EN = VDDI,V_{IN} =VDDI,	I_{DD1}	2.27		mA
	I_{DD2}	2.30		mA
Supply current: 1 Mbps square wave clock input AC signal.	I_{DD1}	1.79		mA

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Parameter	Symbol	Typ.	Max.	Unit
All channels switching with 1 Mbps square wave input, C_L = 15 pF	I_{DD2}	1.83		mA
Supply current: 10 Mbps square wave clock input AC signal. All channels switching with 10 Mbps square wave input, C_L = 15 pF	I_{DD1}	2.21		mA
	I_{DD2}	2.25		mA
CMT8022NXL				
Supply current EN = VDDI, V_{IN} =0 V	I_{DD1}	1.13		mA
	I_{DD2}	1.13		mA
Supply current: device is disabled. EN = VDDI, V_{IN} =VDDI,	I_{DD1}	2.35		mA
	I_{DD2}	2.30		mA
Supply current: 1 Mbps square wave clock input AC signal. All channels switching with 1 Mbps square wave input, C_L = 15 pF	I_{DD1}	1.83		mA
	I_{DD2}	1.82		mA
Supply current: 10 Mbps square wave clock input AC signal. All channels switching with 10 Mbps square wave input, C_L = 15 pF	I_{DD1}	2.25		mA
	I_{DD2}	2.24		mA

Table 7. Supply Current with 5 V Supply- Characteristics of CMT802XNXL

Parameters	Symbol	Condition	Min.	Typ.	Max.	Unit
Data rate	DR		0		10	Mbps
Minimum pulse width	PW	See figure 6, C_L = 15 pF		5	5	ns
Propagation delay rising	t_{PLH}	See figure 6, C_L = 15 pF		9	15	ns
Propagation delay falling	t_{PHL}	See figure 6, C_L = 15 pF		9	15	ns
Pulse width distortion |t PHL – t PLH |	PWD	See figure 6, C_L = 15 pF			5	ns
Rising time	tr	See figure 6, C_L = 15 pF			5	ns
Falling time	tf	See figure 6, C_L = 15 pF			5	ns
Peak eye diagram Jitter	t_{JIT}(PK)			400		ps
Channel-to-channel delay Skew	t_{SK}(c2c)			1.5	2.5	ns
Part-to-part delay skew	t_{SK}(p2p)				5	ns

10.3 Supply Current Characteristics with 3.3 V Supply

VDD1 = VDD2 = 3.3V, T_A= -40 to 125 ℃.

Table 8. Supply Current Characteristics with 3.3 V Supply

Parameter	Symbol	Typ.	Max.	Unit
CMT8020NXL				
Supply current EN = VDDI,V_{IN} =0 V	I_{DD1}	0.67		mA
	I_{DD2}	1.14		mA
Supply current: device is disabled. EN = VDDI,V_{IN} =VDDI,	I_{DD1}	2.94		mA
	I_{DD2}	1.18		mA

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Parameter	Symbol	Typ.	Max.	Unit
Supply current: 1 Mbps square wave clock input AC signal. All channels switching with 1 Mbps square wave input, C_L = 15 pF	I_{DD1}	1.80		mA
	I_{DD2}	1.27		mA
Supply current: 10 Mbps square wave clock input AC signal. All channels switching with 10 Mbps square wave input, C_L = 15 pF	I_{DD1}	1.83		mA
	I_{DD2}	2.26		mA
CMT8021NXL				
Supply current EN = VDDI,V_{IN} =0 V	I_{DD1}	1.12		mA
	I_{DD2}	1.13		mA
Supply current: device is disabled. EN = VDDI,V_{IN} =VDDI,	I_{DD1}	2.25		mA
	I_{DD2}	2.29		mA
Supply current: 1 Mbps square wave clock input AC signal. All channels switching with 1 Mbps square wave input, C_L = 15 pF	I_{DD1}	1.71		mA
	I_{DD2}	1.75		mA
Supply current: 10 Mbps square wave clock input AC signal. All channels switching with 10 Mbps square wave input, C_L = 15 pF	I_{DD1}	2.01		mA
	I_{DD2}	2.05		mA
CMT8022NXL				
Supply current EN = VDDI,V_{IN} =0 V	I_{DD1}	1.14		mA
	I_{DD2}	1.14		mA
Supply current: device is disabled. EN = VDDI,V_{IN} =VDDI,	I_{DD1}	2.33		mA
	I_{DD2}	2.31		mA
Supply current: 1 Mbps square wave clock input AC signal. All channels switching with 1 Mbps square wave input, C_L = 15 pF	I_{DD1}	1.75		mA
	I_{DD2}	1.74		mA
Supply current: 10 Mbps square wave clock input AC signal. All channels switching with 10 Mbps square wave input, C_L = 15 pF	I_{DD1}	2.04		mA
	I_{DD2}	2.03		mA

Table 9. Supply Current with 3.3 V Supply - Characteristics of CMT802XNXL

Parameters	Symbol	Condition	Min.	Typ.	Max.	Unit
Data rate	DR		0		10	Mbps
Minimum pulse width	PW	See figure 9, CL = 15 pF		5		ns
Propagation delay rising	t_{PLH}	See figure 9, CL = 15 pF		9	15	ns
Propagation delay falling	t_{PHL}	See figure 9, CL = 15 pF		9	15	ns
Pulse width distortion |t PHL – t PLH |	PWD	See figure 9, CL = 15 pF			5	ns
Rising time	tr	See figure 9, CL = 15 pF			5	ns
Falling time	tf	See figure 9, CL = 15 pF			5	ns
Peak eye diagram Jitter	t_{JIT}(PK)			400		ps
Channel-to-channel Delay Skew	t_{SK}(c2c)			1.5	2.5	ns
Part-to-part delay skew	t_{SK}(p2p)				5	ns

10.4 Supply Current Characteristics with 2.5 V Supply

VDD1 = VDD2 = 2.5 V, T_A= -40 to 125 ℃.

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Table 10. Supply Current Characteristics with 2.5 V Supply

Parameter	Symbol	Typ.	Max.	Unit
CMT8020NXL				
Supply current EN = VDDI,V_{IN} =0 V	I_{DD1}	0.66		mA
	I_{DD2}	1.13		mA
Supply current: device is disabled. EN = VDDI,V_{IN} =VDDI,	I_{DD1}	2.93		mA
	I_{DD2}	1.18		mA
Supply current: 1 Mbps square wave clock input AC signal. All channels switching with 1 Mbps square wave input, C_L = 15 pF	I_{DD1}	1.79		mA
	I_{DD2}	1.24		mA
Supply current: 10 Mbps square wave clock input AC signal. All channels switching with 10 Mbps square wave input, C_L = 15 pF	I_{DD1}	1.82		mA
	I_{DD2}	2.00		mA
CMT8021NXL				
Supply current EN = VDDI,V_{IN} =0 V	I_{DD1}	1.11		mA
	I_{DD2}	1.13		mA
Supply current: device is disabled. EN = VDDI,V_{IN} =VDDI,	I_{DD1}	2.24		mA
	I_{DD2}	2.28		mA
Supply current: 1 Mbps square wave clock input AC signal. All channels switching with 1 Mbps square wave input, C_L = 15 pF	I_{DD1}	1.65		mA
	I_{DD2}	1.69		mA
Supply current: 10 Mbps square wave clock input AC signal. All channels switching with 10 Mbps square wave input, C_L = 15 pF	I_{DD1}	1.86		mA
	I_{DD2}	1.90		mA
CMT8022NXL				
Supply current EN = VDDI,V_{IN} =0 V	I_{DD1}	1.14		mA
	I_{DD2}	1.13		mA
Supply current: device is disabled. EN = VDDI,V_{IN} =VDDI,	I_{DD1}	2.32		mA
	I_{DD2}	2.30		mA
Supply current: 1 Mbps square wave clock input AC signal. All channels switching with 1 Mbps square wave input, C_L = 15 pF	I_{DD1}	1.74		mA
	I_{DD2}	1.72		mA
Supply current: 10 Mbps square wave clock input AC signal. All channels switching with 10 Mbps square wave input, C_L = 15 pF	I_{DD1}	1.94		mA
	I_{DD2}	1.92		mA

Table 11. Supply Current with 2.5 V Supply - Characteristics of CMT802XNXL

Parameters	Symbol	Condition	Min.	Typ.	Max.	Unit
Data rate	DR		0		10	Mbps
Minimum pulse width	PW	See figure 9, C_L = 15 pF		5	5	ns
Propagation delay rising	t_{PLH}	See figure 9, C_L = 15 pF		9	15	ns
Propagation delay falling	t_{PHL}	See figure 9, C_L = 15 pF		9	15	ns
Pulse width distortion |t PHL – t PLH |	PWD	See figure 9, C_L = 15 pF			5	ns
Rising time	tr	See figure 9, C_L = 15 pF			5	ns

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Parameters	Symbol	Condition	Min.	Typ.	Max.	Unit
Falling time	t_f	See figure 9, C_L = 15 pF			5	ns
Peak eye diagram Jitter	t_{JIT}(PK)			400		ps
Channel-to-channel Delay Skew	t_{SK}(c2c)			1.5	2.5	ns
Part-to-part delay skew	t_{SK}(p2p)				5	ns

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10.5 Typical Characteristics

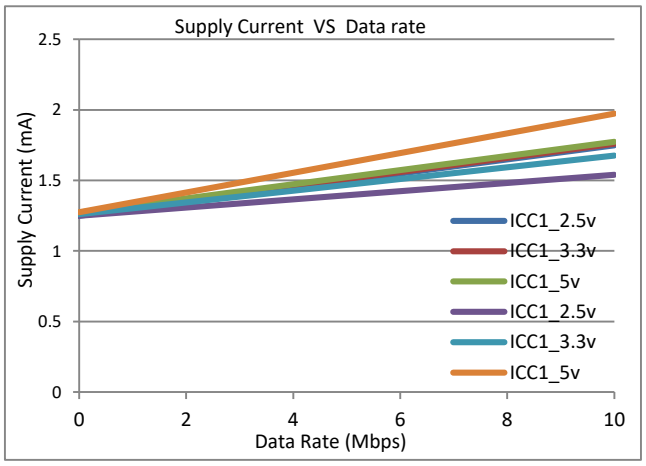


Figure 11. Supply Current vs. Data Rate (with 15-pF Load) T_A=25℃ C_L=15pF

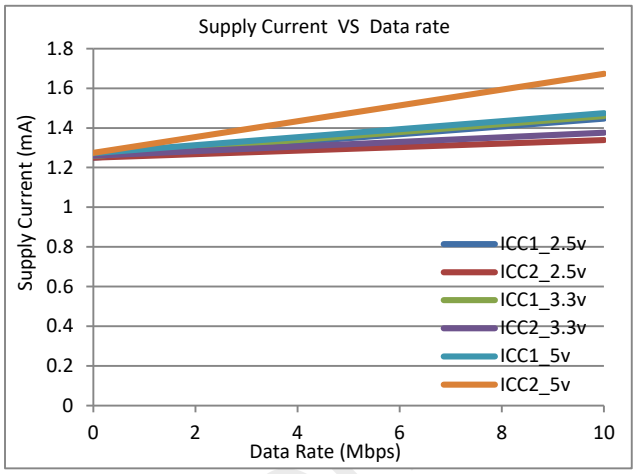


Figure 12. Supply Current vs. Data Rate (with No Load) T_A=25℃ C_L=No Load

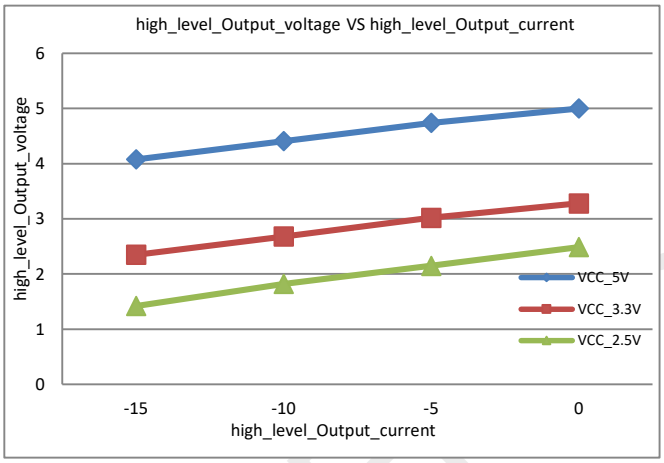


Figure 13. High-Level Output Voltage vs. High-Level Output Current (T_A=25℃)

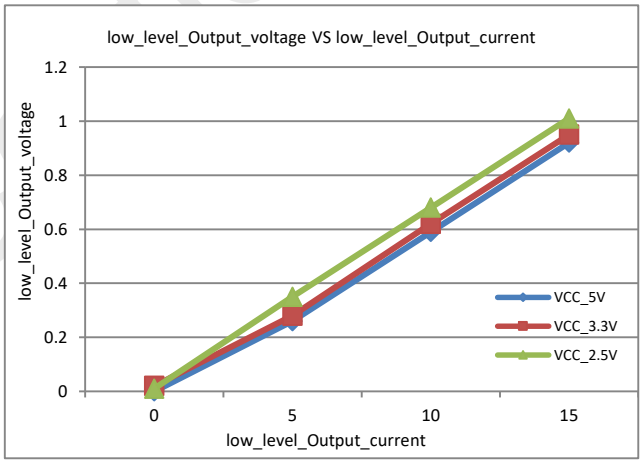


Figure 14. Low-Level Output Voltage vs. Low-Level Output Current(T_A=25℃)

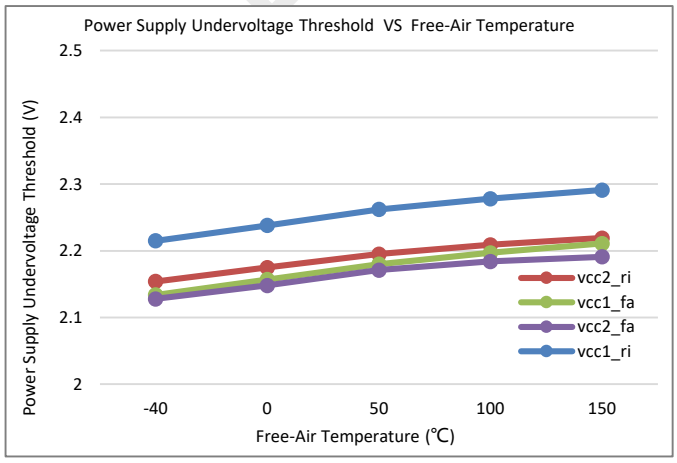


Figure 15. Power Supply Under-voltage Threshold vs. Free-Air Temperature

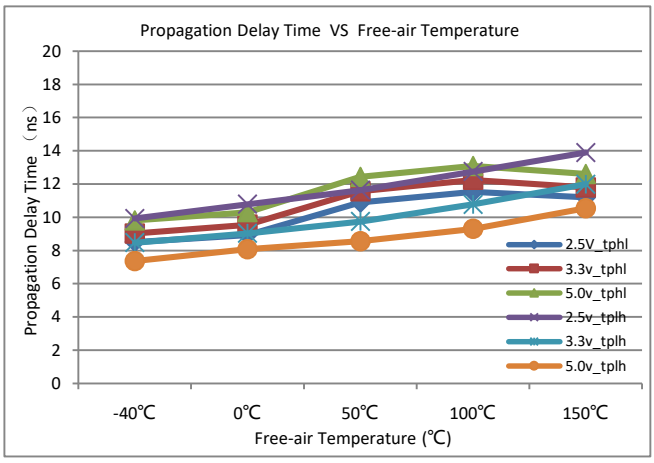


Figure 16. Propagation Delay Time vs. Free-Air Temperature

10.6 Insulation Specifications

Table 12. Insulation Specifications

Parameters	Sym.	Condition	Value	Unit
			NB SOIC-8	
External clearance[1]	CLR	The shortest terminal-to-terminal distance through air	4.0	mm
External creepage[1]	CRP	The shortest terminal-to-terminal distance across the package surface	4.0	mm
Distance through insulation	DTI	Minimum internal gap	20	um
Comparative tracking index	CTI	DIN EN 60112 (VDE 0303-11);IEC 60112	> 400	V
Material group	-		II	-
Overvoltage category per IEC 60664-1	-	Rated mains voltage ⩽ 300 V_{RMS}	I	-
		Rated mains voltage ⩽ 600 V_{RMS}	I-IV	-
		Rated mains voltage ⩽ 1000 V_{RMS}	I-III	-
DIN VDE V 0884-11:2017-01[2]				
Maximum repetitive isolation voltage	V_{IORM}		565	V_{pk}
Maximum isolation working voltage	V_{IOWM}	AC voltage (sine wave); Time dependent dielectric breakdown (TDDB) test	400	V_{RMS}
		DC voltage	565	V_{DC}
Maximum transient isolation voltage	V_{IOTM}	V_{TEST} = V_{IOTM},t = 60 s (qualification); t = 1 s (100% production)	5300	V_{pk}
Maximum surge isolation voltage[3]	V_{IOSM}	Test method per IEC60065, 1.2/50 us waveform, V_{TEST} = 1.6 x V_{IOSM} (qualification)	5384	V_{pk}
Apparent charge[4]	q_{pd}	Method a: After I/O safety test subgroup 2/3, V_{ini} = V_{IOTM}, t_{ini} = 60 s; $V_{pd(m)}$ = 1.2 × V_{IORM}, t_m = 10 s	⩽5	⩽5pC
		Method a: After environmental tests subgroup 1, V_{ini} = V_{IOTM}, t_{ini} = 60 s; $V_{pd(m)}$ = 1.6 × V_{IORM}, t_m = 10 s	⩽5	
		Method b1: At routine test (100% production) and preconditioning (type test) V_{ini} = V_{IOTM}, t_{ini} = 1 s; $V_{pd(m)}$ = 1.875 × V_{IORM}, t_m = 1 s	⩽5	
Isolation capacitance, input to output[5]	C_{IO}	V_{IO} = 0.4 x sin (2πft), f = 1 MHz	0.6	pF
Isolation resistance, input to output[5]	R_{IO}	V_{IO} = 500 V	$>10^{10}$	Ω
Withstand isolation voltage	V_{ISO}	V_{TEST} = V_{ISO}, t = 60 s (qualification); V_{TEST} = 1.2 × V_{ISO}, t = 1 s (100% production)	3750	V_{RMS}

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Notes:

[1]. Creepage and clearance requirements should be applied according to the specific equipment isolation standards of an application. Care should be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the printed-circuit board do not reduce this distance. Creepage and clearance on a printed-circuit board become equal in certain cases. Techniques such as inserting grooves and/or ribs on a printed-circuit board are used to help increase these specifications.

[2]. This coupler is suitable for safe electrical insulation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

[3]. Testing is carried out in air or oil to determine the intrinsic surge immunity of the isolation barrier.

[4]. Apparent charge is electrical discharge caused by a partial discharge (pd).

[5]. All pins on each side of the barrier are tied together creating a two-terminal device.

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10.7 Safety-related Certifications

Table 13. Safety-related Certifications

VDE	UL		CQC	TUV
DIN VDE V0884-11:2017-01 （Patents pending）	UL 1577 Component Recognition Program	Approved under CSA Component Acceptance Notice 5A	GB 4943.1-2011	EN 61010-1:2010 (3rd Ed) and EN 60950-1:2006/A2: 2013 （Patents pending）
Certificate number: pending	Certificate number: E541580		Certificate number: CQC23001382478	Client ID number: pending

10.8 Safety Limiting Values

Safety limiting intends to minimize potential damage to the isolation barrier upon failure of input or output circuitry. A failure of the I/O can allow low resistance to ground or the supply and, without current limiting, dissipate sufficient power to overheat the die and damage the isolation barrier potentially leading to secondary system failures

Table 14. Safety Limiting Values

Parameters	Symbol	Test Condition	Value	Unit
			NB SOIC-16	
Safety input, output, or supply current	Is	$R_{\theta JA}$ = 140 °C/W, V_I = 5.5 V, T_J = 125 °C, T_A = 25 °C	160	mA
		$R_{\theta JA}$ = 84 °C/W, V_I = 5.5 V, T_J = 125 °C, T_A = 25 °C		mA
Total power dissipation at 25℃	Ps			W
Case temperature	Ts		125	℃

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10.9 Thermal Information

Table 15. Thermal Information

Parameter	Symbol	Value		Unit
		NB SOIC-16	WB SOIC-16	
Junction-to-ambient thermal resistance	θ_{JA}	78.9	78.9	°C/W
Junction-to-case (top) thermal resistance	$\theta_{JC\ (top)}$	41.1	41.6	°C/W
Junction-to-board thermal resistance	θ_{JB}	49.5	43.6	°C/W

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11 Function Description

11.1 Function Overview

The CMT802XNXL device is a high-performance, quad-channel digital isolator with 3750 V_{RMS} isolation rating. The CMT802XNXL has an On-Off keying (OOK) modulation scheme to transmit the digital data across a silicon dioxide based isolation barrier. The transmitter sends a high-frequency carrier across the barrier to represent one digital state and sends no signal to represent the other digital state. The receiver demodulates the signal after advanced signal conditioning and produces the output through a buffer stage. If the ENx pin is low then the output goes to high impedance. The CMT802XNXL also incorporates advanced circuit techniques to maximize the CMTI performance and minimize the radiated emissions due to the high frequency carrier and IO buffer switching. The figure below shows a conceptual detail of how the On-Off keying scheme works.

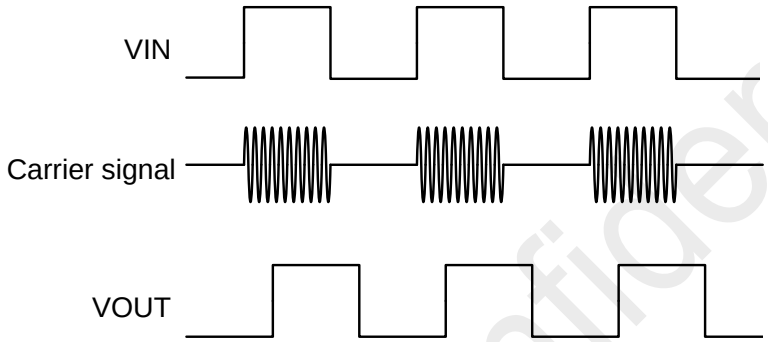


Figure 17. On-Off Keying Based Modulation Scheme

11.2 Functional Modes

The table below lists the functional modes of the CMT802XNXL.

Table 16. Function Table[1]

V_{DD1}	V_{DD2}	Input (INx)[2]	Output (OUTx)	Comment
PU	PU	H	H	Normal operation: A channel output assumes the logic state of its input
		L	L	
		Open	Default	Default mode: when INx is open, the corresponding channel output goes to its default logic state
PD	PU	X	Default	Default mode: when VDDI is unpowered, a channel output assumes the logic state based on the selected default option. When VDD1 transitions from unpowered to powered-up, a channel output assumes the logic state of the input. When VDD1 transitions from powered-up to unpowered, channel output assumes the selected default state
X	PD	X	Undetermined	When VDD2 is unpowered, a channel output is undetermined[3]. When VDD2 transitions from unpowered to powered-up, a channel output assumes the logic state of the input

11.3 Insulation Lifetime

Insulation lifetime projection data is collected by using industry-standard Time Dependent Dielectric Breakdown (TDDB) test method. In this test, all pins on each side of the barrier are tied together creating a two-terminal device and high voltage applied between the two sides; See the figure below for TDDB test setup. The insulation breakdown data is collected at various high voltages switching at 60 Hz over temperature. For reinforced insulation, VDE standard requires the use of TDDB projection line

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with failure rate of less than 1 part per million (ppm). Even though the expected minimum insulation lifetime is 20 years at the specified working isolation voltage, VDE reinforced certification requires additional safety margin of 20% for working voltage and 87.5% for lifetime which translates into minimum required insulation lifetime of 37.5 years at a working voltage that's 20% higher than the specified value.

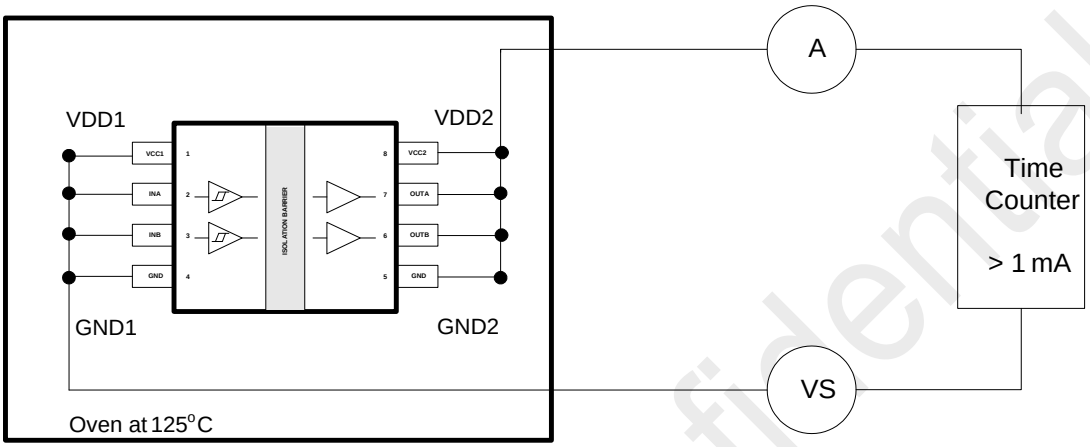


Figure 18. Test Setup for Insulation Lifetime Measurement

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12 Packaging Information

The packaging information of the CMT802XNXL is shown in the figures below.

12.1 CMT802XNXL Narrow Body SOIC-8 Packaging

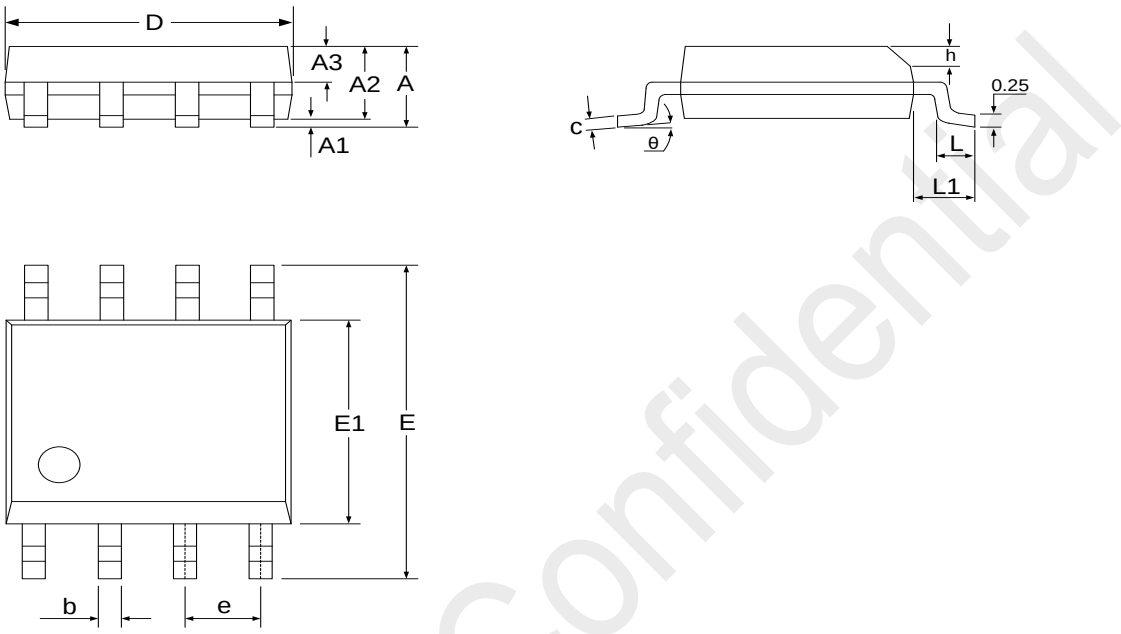


Figure 19. Narrow Body SOIC-8 Packaging

Table 17.Narrow Body SOIC-8 Packaging Scale

Symbol	Scale (mm)		
	Min.	Typ.	Max.
A	-	-	1.75
A1	0.10	-	0.225
A2	1.30	1.40	1.50
A3	0.60	0.65	0.70
b	0.39	-	0.48
c	0.21	-	0.26
D	4.70	4.90	5.10
E	5.80	6.00	6.20
E1	3.70	3.90	4.10
e	1.27 BSC		
h	0.25	-	0.50
L	0.50	-	0.80
L1	1.05 BSC		
θ	0	-	8°

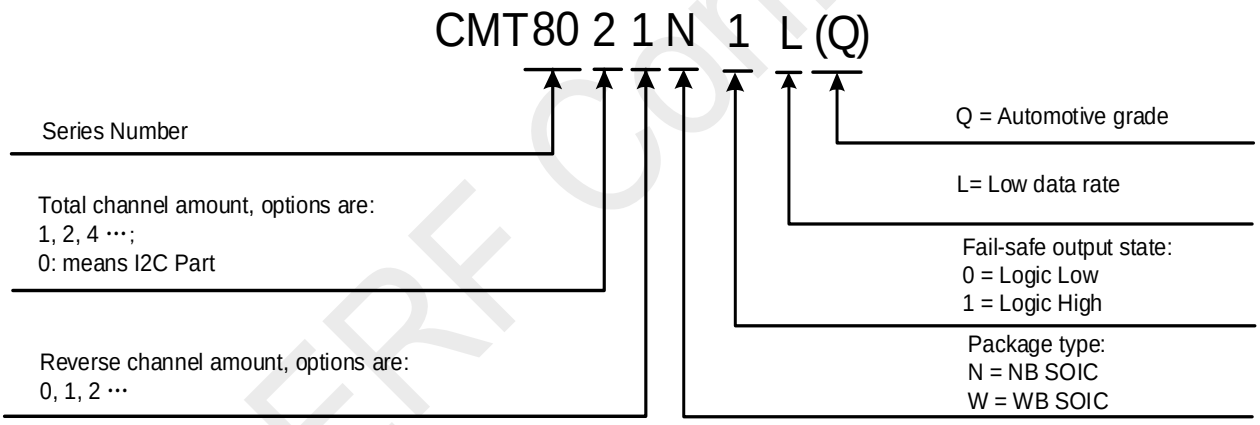
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13 Ordering Information

Table 18. Part Number List

Part Number	Min. Order Quantity	Withstand Voltage（rms）	Numbers of Total Channels	Data Rate (Mbps)	Default Output State	Package	MSL
CMT8020N0L	3000	3750	2	10	Low	NB SOIC-8	1
CMT8020N1L	3000	3750	2	10	High	NB SOIC-8	1
CMT8021N0L	3000	3750	2	10	Low	NB SOIC-8	1
CMT8021N1L	3000	3750	2	10	High	NB SOIC-8	1
CMT8022N0L	3000	3750	2	10	Low	NB SOIC-8	1
CMT8022N1L	3000	3750	2	10	High	NB SOIC-8	1

Part Number Naming Rule:



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Please visit www.hoperf.com for more product/product line information.

Please contact sales@hoperf.com or your local sales representative for sales or pricing requirements.

14 Tape and Reel Information

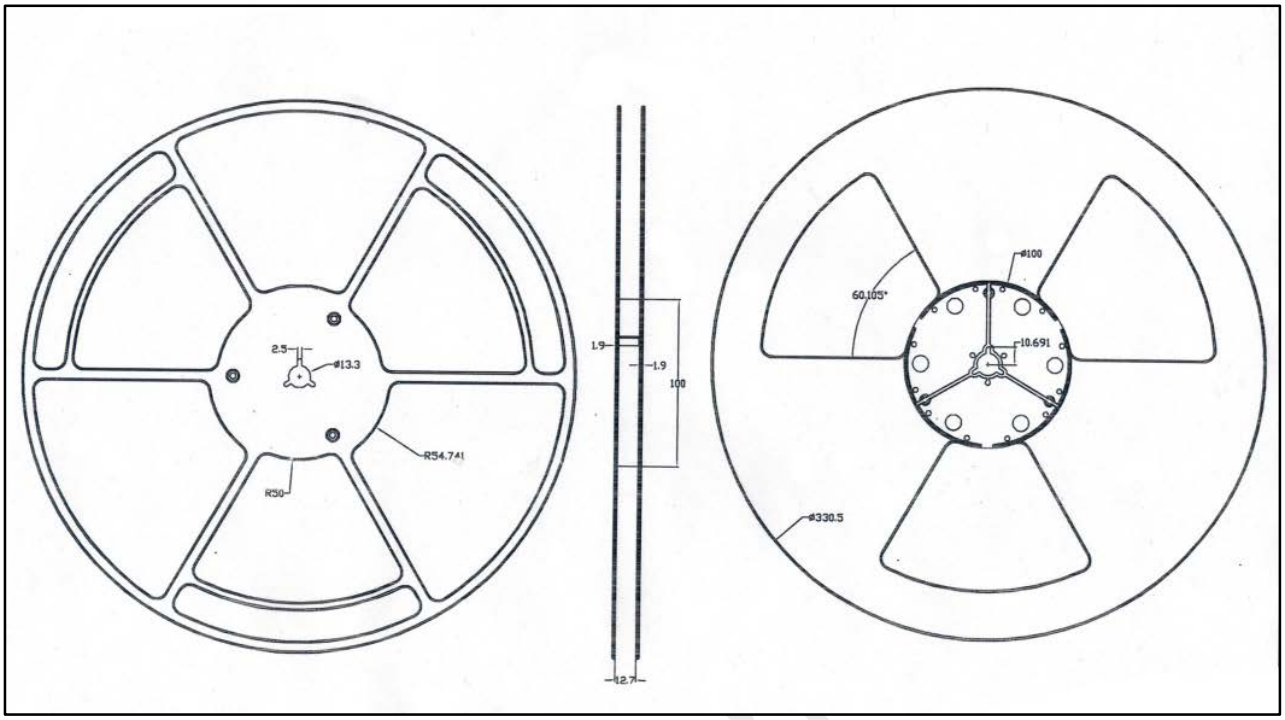


Figure 22. CMT802XNXL SOIC-8 Tape & Reel Information

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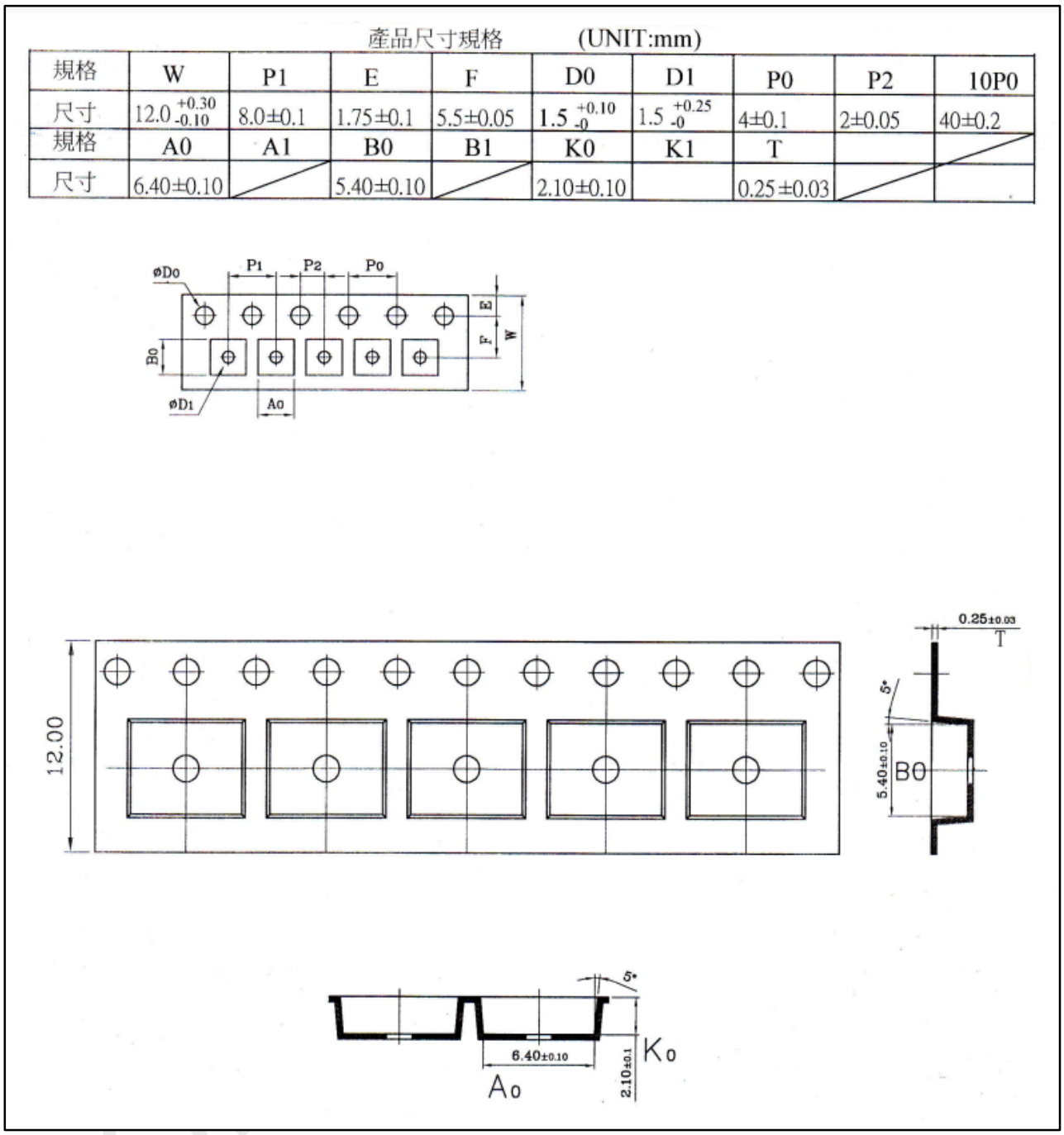


Figure 23. CMT802XNXL SOIC-8 Tape & Reel Information

15 Revise History

Table 19. Revise Record

Version No.	Chapter	Description	Date
0.1	All	Initial version	2023/03/23
0.2	All	Delete the silver printing section	2023/04/20
		Added the CQC cercificate number	
0.3	All	Modified the data rate of 5 Mbps to 10 Mbps.	2023/11/28
		Add MSL level in order information	2024/12/03
		Modified the data rate	2025/7/9
0.4	10.5	Modify the typical performance curve of power supply current VS. data rate	2025/7/11

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16 Contacts

Shenzhen Hope Microelectronics Co., Ltd.
Address: 30th floor of 8th Building, C Zone, Vanke Cloud City, Xili Sub-district, Nanshan, Shenzhen, GD, P.R. China

Tel: +86-755-82973805 / 4001-189-180
Fax: +86-755-82973550
Post Code: 518052
Sales: sales@hoperf.com
Website: www.hoperf.com

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